NSN 5961-01-512-9719

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-512-9719 **Inclosure Material:** Glass **Overall Length:** Between 0.200 inches and 0.225 inches **Mounting Method:** Compression **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 16.4 breakdown voltage, dc and 15.0 working peak reverse voltage **Current Rating Per Characteristic:** 500.00 microamperes forward current, average peak and 63.00 milliamperes forward current, average major **Special Features:** Surface mounted square end cap diodes **Terminal Type And Quantity:** 2 bonding pad Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: